

Date:- 14th June, 2017

Data Sheet Issue:- 3

Rectifier Diode Types W1975MC650 to W1975MC720

Development part number WX362MC720

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	6500-7200	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	6600-7300	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
I _{F(AV)M}	Maximum average forward current, T _{sink} =55°C, (note 2)	1975	Α
I _{F(AV)M}	Maximum average forward current. T _{sink} =100°C, (note 2)	1350	Α
I _{F(AV)M}	Maximum average forward current. T _{sink} =100°C, (note 3)	840	Α
I _{F(RMS)M}	Nominal RMS forward current, T _{sink} =25°C, (note 2)	3630	Α
I _{F(d.c.)}	D.C. forward current, T _{sink} =25°C, (note 4)	2310	Α
I _{FSM}	Peak non-repetitive surge t _p =10ms, V _{rm} =60%V _{RRM} , (note 5)	18000	Α
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _{rm} ≤10V, (note 5)	20000	Α
l ² t	$I^{2}t$ capacity for fusing t_{p} =10ms, V_{rm} =60% V_{RRM} , (note 5)	1.62×10 ⁶	A ² s
I ² t	l²t capacity for fusing t _p =10ms, V _{rm} ≤10V, (note 5)	2.00×10 ⁶	A ² s
T _{j op}	Operating temperature range	-40 to +150	°C
T _{stg}	Storage temperature range	-55 to +150	°C

Notes:-

- 1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Cathode side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, 150°C T_j initial.



Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{FM}	Maximum peak forward voltage	-	-	2.25	I _{FM} =2500A	V
V_{FM}	Maximum peak forward voltage	-	-	3.95	I _{FM} =4200A	V
V_{T0}	Threshold voltage	-	-	0.95		V
r _T	Slope resistance	-	-	0.51		mΩ
I _{RRM}	Peak reverse current	-	-	100	Rated V _{RRM}	mA
Qrr	Recovered charge	-	8700	9500		μC
Q _{ra}	Recovered charge, 50% Chord	-	4160	-	 I _{TM} =1000A, t _p =1000μs, di/dt=10A/μs,	μC
I _{rm}	Reverse recovery current	-	185	-	V _r =100V	
t _{rr}	Reverse recovery time, 50% chord	-	45	-		μs
		-	-	0.0140	Double side cooled	K/W
RthJK	Thermal resistance, junction to heatsink	-	-	0.0265	Anode side cooled	K/W
		-	-	0.0297	Cathode side cooled	K/W
F	Mounting force	25	-	31	Note 2	kN
Wt	Weight		530			g

Notes:-

- Unless otherwise indicated T_j=150°C.
 For other clamp forces, please consult factory.



Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V _{RRM} V	V _{RSM} V	V _R DC V
65	6500	6600	4350
68	6800	6900	4550
72	7200	7300	4800

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_i below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{{V_{T0}}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \qquad W_{AV} = \frac{\Delta T}{R_{th}}$$
 and:
$$\Delta T = T_{j \max} - T_K$$

Where $V_{T0}=0.95 \text{ V}$, $r_{T}=0.51 \text{ m}\Omega$,

 R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance					
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.	
Square wave Double Side Cooled	0.01665	0.01581	0.01516	0.0140	
Square wave Cathode Side Cooled	0.03217	0.03147	0.03090	0.0297	
Sine wave Double Side Cooled	0.01612	0.01531	0.01436		
Sine wave Cathode Side Cooled	0.03174	0.03105	0.03022		

Form Factors					
Conduction Angle 6 phase (60°) 3 phase (120°) ½ wave (180°) d.c.					
Square wave	2.449	1.732	1.414	1	
Sine wave	2.778	1.879	1.57		



5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F, on page 6 is represented in two ways;

- (i) the well established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	150°C Coefficients
Α	0.5160004	0.1568668
В	0.07006873	0.1159272
С	2.54996×10 ⁻⁴	4.47058×10 ⁻⁴
D	3.010536×10 ⁻³	1.376798×10 ⁻³



5.3 D.C. Thermal Impedance Calculation

$$r_{t} = \sum_{p=1}^{p=n} r_{p} \cdot \left(1 - e^{\frac{-t}{\tau_{p}}}\right)$$

Where p = 1 to n, n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

 r_{t} = Thermal resistance at time t.

 r_p = Amplitude of p_{th} term.

 τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Double Side Cooled						
Term 1 2 3 4						
r_p	8.594785×10 ⁻³	3.308247×10 ⁻³	1.039072×10 ⁻³	7.916582×10 ⁻⁴		
$ au_{\mathcal{P}}$	0.7185764	0.09970181	0.02165834	5.266433×10 ⁻³		

Term	1	2	3
r_p	0.02196926	5.845724×10 ⁻³	1.904897×10 ⁻³
$ au_{p}$	4.127141	0.1629998	8.832583×10 ⁻³

6.0 Reverse recovery ratings

(i) Qra is based on 50% Irm chord as shown in Fig. 1

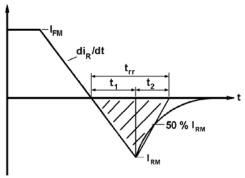


Fig. 1

$$Q_{rr} = \int_{0}^{150 \,\mu s} i_{rr}.dt$$

(iii)
$$K Factor = \frac{t_1}{t_2}$$



Curves

Figure 1 – Forward characteristics of Limit device

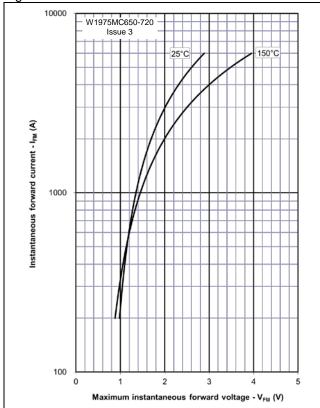


Figure 2 – Transient thermal impedance

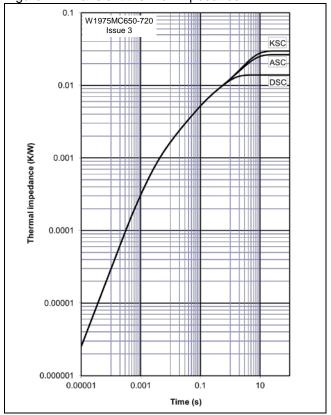


Figure 3 - Maximum Surge Rating

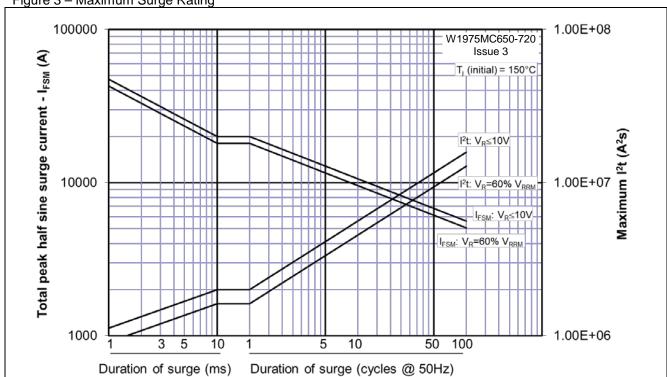




Figure 4 - Total recovered charge, Q_{rr}

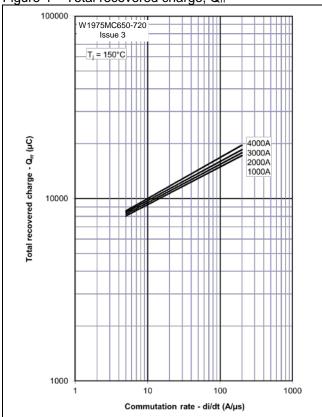


Figure 5 – Recovered charge, Qra (50% chord)

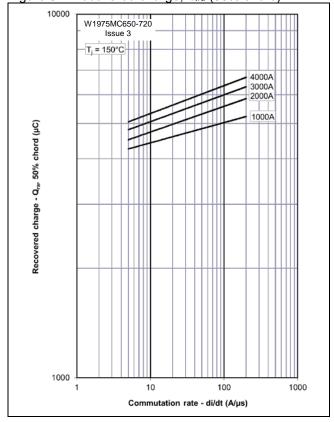


Figure 6 - Peak reverse recovery current, Irm

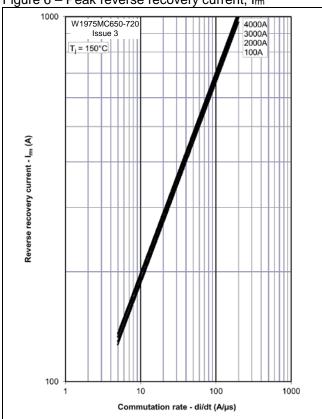


Figure 7 – Maximum recovery time, t_{rr} (50% chord)

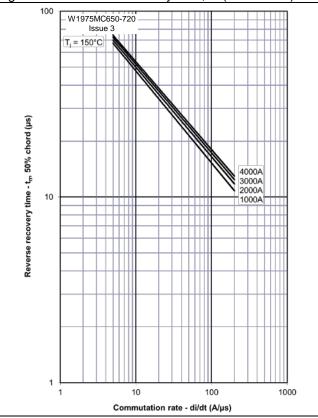




Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

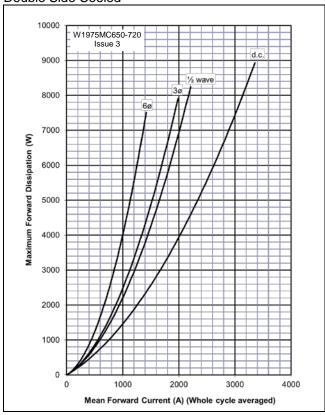


Figure 10 – Forward current vs. Power dissipation – Cathode Side Cooled

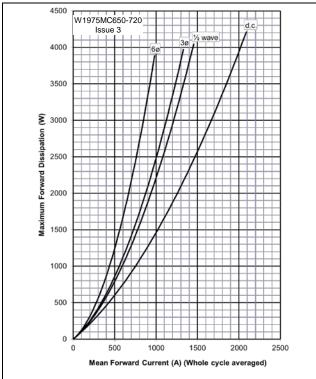


Figure 9 – Forward current vs. Heatsink temperature – Double Side Cooled

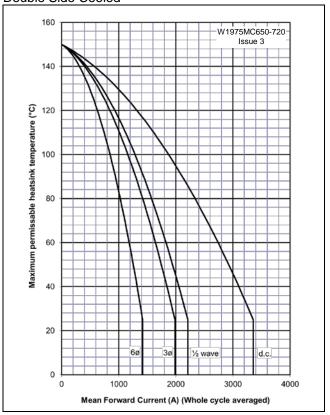
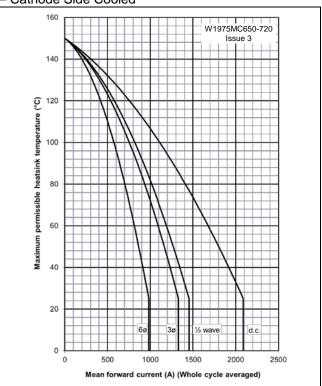
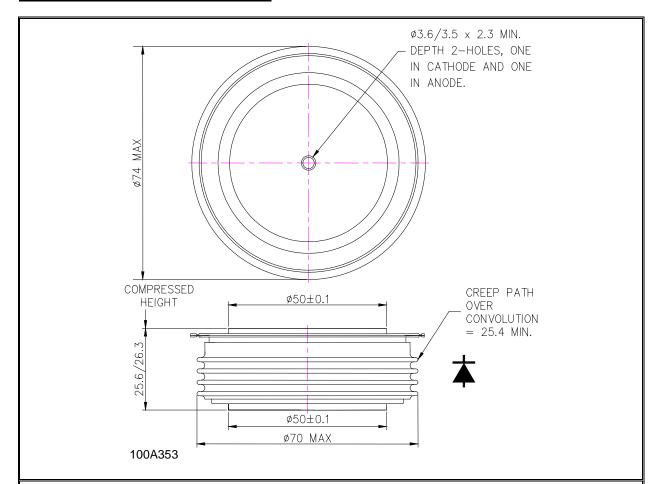


Figure 11 – Forward current vs. Heatsink temperature – Cathode Side Cooled





Outline Drawing & Ordering Information



ORDERING INFORMATION

(Please quote 10 digit code as below)

W1975	MC	**	0
Fixed Type Code	Fixed Outline Code	Voltage code V _{RRM} /100 72	Fixed code

Order code: W1975MC720- 7200V V_{RRM}, 26.3mm clamp height capsule.

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